



# High Speed CMOS Logic – 74HC139

## Dual 1-of-4 Decoder / Demultiplexer in bare die form

Rev 1.1  
21/07/20

### Description

The 74HC139 is fabricated using a 2.5µm 5V CMOS process and has the same high speed performance of LSTTL combined with CMOS low power consumption. This device consists of x2 independent 1-of-4 decoders, each decoding a 2 bit address to 1-of-4 active-low outputs. Active-low Selects facilitate the demultiplexing and cascading functions. The demultiplexing function is executed by using the Address inputs to select the desired device output and utilizing the Select as a data input.

### Features:

- Output Drive Capability: 10 LSTTL Loads
- Low Input Current: 1µA
- Outputs directly interface CMOS, NMOS and TTL
- Operating Voltage Range: 2V to 6V
- CMOS High Noise Immunity
- Function compatible with 74LS139.

### Ordering Information

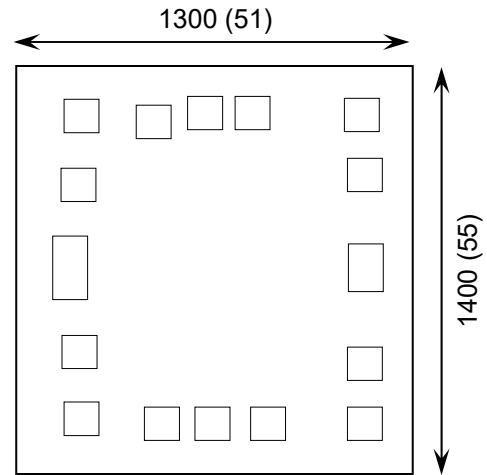
The following part suffixes apply:

- No suffix - MIL-STD-883 /2010B Visual Inspection

For High Reliability versions of this product please see

[54HC139](#)

### Die Dimensions in µm (mils)



### Supply Formats:

- Default – Die in Waffle Pack (400 per tray capacity)
- ~~\*\*\*~~ Sawn Wafer on Tape – On request
- Unsawn Wafer – On request
- Die Thickness <=> 350µm(14 Mils) – On request
- Assembled into Ceramic Package – On request

### Mechanical Specification

Die Size (Unsawn)	1300 x 1400 51 x 55	µm mils
Minimum Bond Pad Size	106 x 106 4.17 x 4.17	µm mils
Die Thickness	350 (±20) 13.78 (±0.79)	µm mils
Top Metal Composition	Al 1%Si 1.1µm	
Back Metal Composition	N/A – Bare Si	

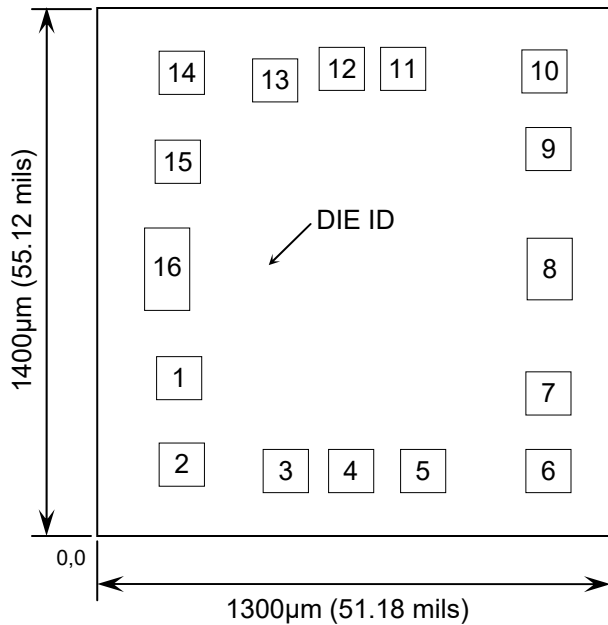




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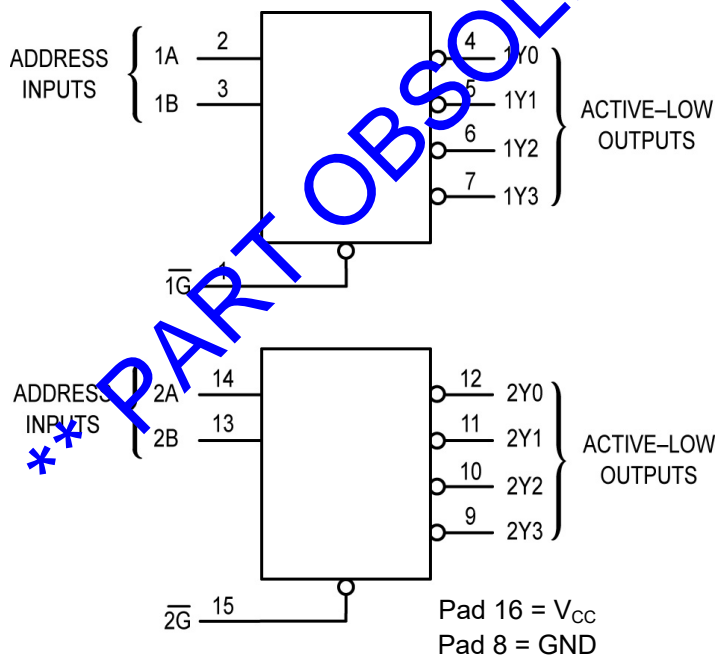
## Pad Layout and Functions



PAD	FUNCTION	COORDINATES (mm)	
		X	Y
1	$\overline{1G}$	0.152	0.366
2	1A	0.162	0.132
3	1B	0.422	0.122
4	1Y0	0.59	0.122
5	1Y1	0.772	0.122
6	1Y2	1.088	0.122
7	1Y3	1.088	0.333
8	GND	1.088	0.619
9	2Y3	1.088	0.972
10	2Y2	1.078	1.173
11	2Y1	0.722	1.183
12	2Y0	0.566	1.183
13	2B	0.396	1.153
14	2A	0.162	1.173
15	$\overline{2G}$	0.152	0.938
16	V <sub>CC</sub>	0.122	0.591

CONNECT CHIP BACK TO V<sub>CC</sub> OR FLOAT

## Logic Diagram



## Truth Table

INPUTS			OUTPUTS			
$\overline{G}$	B	A	Y0	Y1	Y2	Y3
H	X	X	H	H	H	H
L	L	L	L	H	H	H
L	L	H	H	L	H	H
L	H	L	H	H	L	H
L	H	H	H	H	H	L

X = don't care





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## Absolute Maximum Ratings<sup>1</sup>

PARAMETER	SYMBOL	VALUE	UNIT
DC Supply Voltage (Referenced to GND)	$V_{CC}$	-0.5 to +7.0	V
DC Input Voltage (Referenced to GND)	$V_{IN}$	-1.5 to $V_{CC} + 1.5$	V
DC Output Voltage (Referenced to GND)	$V_{OUT}$	-0.5 to $V_{CC} + 0.5$	V
DC Input Current, per pin	$I_{IN}$	$\pm 20$	mA
DC Output Current, per pin	$I_{OUT}$	$\pm 25$	mA
DC $V_{CC}$ or GND Current, per pin	$I_{CC}$	$\pm 50$	mA
Power Dissipation in Still Air <sup>2</sup>	$P_D$	750	mW
Storage Temperature Range	$T_{STG}$	-65 to +150	$^{\circ}C$

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. Measured in plastic DIP package, results in die form are dependent on die attach and assembly method.

## Recommended Operating Conditions<sup>3</sup> (Voltages referenced to GND)

PARAMETER	SYMBOL	MIN	MAX	UNITS
DC Supply Voltage	$V_{CC}$	2	6	V
DC Input or Output Voltage	$V_{IN}, V_{OUT}$	0	$V_{CC}$	V
Operating Temperature Range	$T_J$	0	+85	$^{\circ}C$
Input Rise and Fall Time	$V_{CC} = 2.0V$	0	1000	ns
	$V_{CC} = 4.5V$	0	500	
	$V_{CC} = 6.0V$	0	400	

3. This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{IN}$  and  $V_{OUT}$  should be constrained to the range  $GND \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{CC}$ . Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or  $V_{CC}$ ). Unused outputs must be left open.

## DC Electrical Characteristics (Voltages Referenced to GND)

PARAMETER	SYMBOL	$V_{CC}$	CONDITIONS	LIMITS			UNITS
				25 $^{\circ}C$	85 $^{\circ}C$	FULL RANGE <sup>4</sup>	
Minimum High-Level Input Voltage	$V_{IH}$	2.0V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$ $ I_{OUT}  \leq 20\mu A$	1.5	1.5	1.5	V
		4.5V		3.15	3.15	3.15	
		6.0V		4.2	4.2	4.2	
Maximum Low-Level Input Voltage	$V_{IL}$	2.0V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$ $ I_{OUT}  \leq 20\mu A$	0.5	0.5	0.5	V
		4.5V		1.35	1.35	1.35	
		6.0V		1.8	1.8	1.8	

4. 0 $^{\circ}C \leq T_J \leq +85^{\circ}C$





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## DC Electrical Characteristics (Voltages Referenced to GND)

PARAMETER	SYMBOL	V <sub>CC</sub>	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE <sup>4</sup>	
Minimum High-Level Output Voltage	V <sub>OH</sub>	2.0V	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 20μA	1.9	1.9	1.9	V
		4.5V		4.4	4.4	4.4	
		6.0V		5.9	5.9	5.9	
		4.5V	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 4.0mA	3.98	3.84	3.84	
		6.0V	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 5.2mA	5.48	5.34	5.34	
Maximum Low-Level Output Voltage	V <sub>OL</sub>	2.0V	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 20μA	0.1	0.1	0.1	V
		4.5V		0.1	0.1	0.1	
		6.0V		0.1	0.1	0.1	
		4.5V	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 4.0mA	0.26	0.33	0.33	
		6.0V	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 5.2mA	0.26	0.33	0.33	
Maximum Input Leakage Current	I <sub>IN</sub>	6.0V	V <sub>IN</sub> = V <sub>CC</sub> or GND	±0.1	±1.0	±1.0	μA
Maximum Quiescent Supply Current	I <sub>CC</sub>	6.0V	V <sub>IN</sub> = V <sub>CC</sub> or GND  I <sub>OUT</sub>   ≤ 4.0mA	4	40	40	μA

## AC Electrical Characteristics

PARAMETER	SYMBOL	V <sub>CC</sub>	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE <sup>4</sup>	
Maximum Propagation Delay, Select to Output Y (Figure 1, 3)	t <sub>PLT</sub> , t <sub>PHL</sub>	2.0V	C <sub>L</sub> = 50pF, t <sub>r</sub> = t <sub>f</sub> = 6ns	115	145	145	ns
		4.5V		23	29	29	
		6.0V		20	25	25	
Maximum Propagation Delay, Input A to Output Y (Figure 2,3)	t <sub>PLH</sub> , t <sub>PHL</sub>	2.0V	C <sub>L</sub> = 50pF, t <sub>r</sub> = t <sub>f</sub> = 6ns	115	145	145	ns
		4.5V		23	29	29	
		6.0V		20	25	25	
Maximum Output Transition Time, Any Output (Figure 1,3)	t <sub>TLH</sub> , t <sub>THL</sub>	2.0V	C <sub>L</sub> = 50pF, t <sub>r</sub> = t <sub>f</sub> = 6ns	75	95	95	ns
		4.5V		15	19	19	
		6.0V		13	16	16	
Maximum Input Capacitance	C <sub>IN</sub>	-	-	10	10	10	pF
Power Dissipation Capacitance (Per Decoder) <sup>7</sup>	C <sub>PD</sub>	-	T <sub>J</sub> = 25°C, V <sub>CC</sub> = 5.0V	TYPICAL			pF
				55			

6. Not production tested in die form, characterized by chip design and tested in package.

7. Used to determine the no-load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> V<sub>CC</sub><sup>2</sup>f + I<sub>CC</sub> V<sub>CC</sub>.





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## Pad Description

### ADDRESS INPUTS

1A, 1B, 2A, 2B

(Pads 2, 3, 14, 13)

When the respective 1-of-4 decoder is enabled these inputs determine which of its four active-low outputs is selected.

### CONTROL INPUTS

1G, 2G

(Pads 1, 15)

Active-low select inputs. For a low level on this input, the outputs for that particular decoder follow the Address inputs. A high level on this input forces all outputs to a high level.

### OUTPUTS

1Y0, 1Y1, 1Y2, 1Y3, 2Y0, 2Y1, 2Y2, 2Y3

(Pads 4-7, 12, 11, 10, 9)

Active-low outputs. These outputs assume a low level when addressed and the appropriate Select input is active. These outputs remain high when not addressed or the appropriate Select input is inactive.

## Switching Waveforms

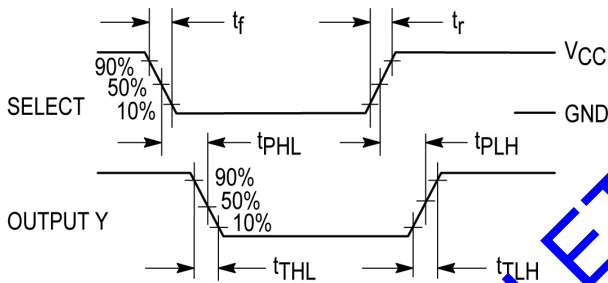


Figure 1

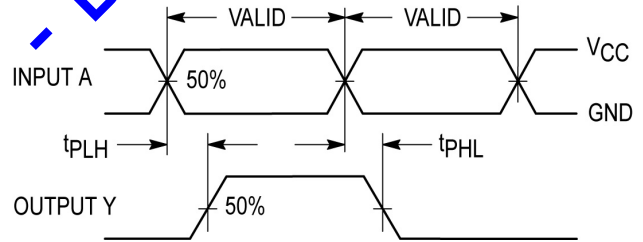
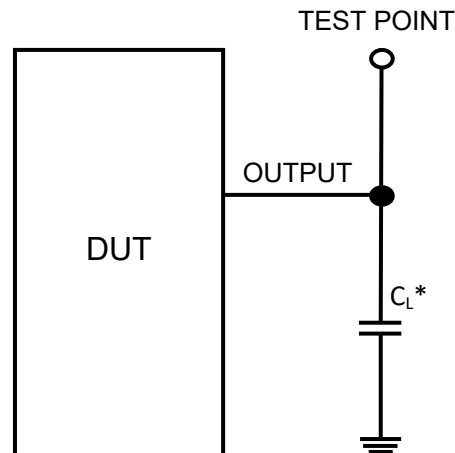


Figure 2

## Test Circuit



\* Includes all probe and jig capacitance





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**\*\* PART OBSOLETE \*\* - DISCONTINUED**

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